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| APPLICATION NO. | FILING DATE | FIRST NAMED INVENTOR | ATTORNEY DOCKET NO. | CONFIRMATION NO. |
|--|-----------------|----------------------|---------------------|------------------|
| 10/756,378 | 01/14/2004 | Jae Gab Lee | 3430-0199P | 2364 |
| 2292 7 | 7590 12/15/2004 | | EXAMINER | |
| BIRCH STEWART KOLASCH & BIRCH | | | BERRY, RENEE R | |
| PO BOX 747 FALLS CHURCH,VA 22040-0747 | | | ART UNIT | PAPER NUMBER |
| | , | | 2818 | |

DATE MAILED: 12/15/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

| | | | _ | | | |
|--|--|---|---|--|--|--|
| | Application No. | Applicant(s) | | | | |
| | 10/756,378 | LEE ET AL. | | | | |
| Office Action Summary | Examiner | Art Unit | | | | |
| | Renee R Berry | 2818 | | | | |
| The MAILING DATE of this communicate Period for Reply | ition appears on the cover sheet wit | h the correspondence address | | | | |
| A SHORTENED STATUTORY PERIOD FOR THE MAILING DATE OF THIS COMMUNICATE. Extensions of time may be available under the provisions of after SIX (6) MONTHS from the mailing date of this communication of the seriod for reply is specified above, the maximum statute. Failure to reply within the set or extended period for reply will Any reply received by the Office later than three months after earned patent term adjustment. See 37 CFR 1.704(b). | ATION. 37 CFR 1.136(a). In no event, however, may a recation. lays, a reply within the statutory minimum of thirty ory period will apply and will expire SIX (6) MON ⁻¹ by statute, cause the application to become ABA | ply be timely filed (30) days will be considered timely. THS from the mailing date of this communication. ANDONED (35 U.S.C. § 133). | | | | |
| Status | | | | | | |
| 1) Responsive to communication(s) filed | on | | | | | |
| | ☐ This action is non-final. | | | | | |
| • • • | Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213. | | | | | |
| Disposition of Claims | | | | | | |
| 4) ⊠ Claim(s) 1-14 is/are pending in the approach 4a) Of the above claim(s) is/are 5) □ Claim(s) 7-14 is/are allowed. 6) ⊠ Claim(s) 1-6 is/are rejected. 7) □ Claim(s) is/are objected to. 8) □ Claim(s) are subject to restriction | withdrawn from consideration. | | | | | |
| Application Papers | | | | | | |
| 9) ☐ The specification is objected to by the E 10) ☑ The drawing(s) filed on 21 January 200 Applicant may not request that any objection Replacement drawing sheet(s) including the specific contents of the specific contents are specifically including the specific contents. | ½ is/are: a) accepted or b) old of the drawing(s) be held in abeyange correction is required if the drawing(s) | ce. See 37 CFR 1.85(a). s) is objected to. See 37 CFR 1.121(d). | | | | |
| Priority under 35 U.S.C. § 119 | | • | | | | |
| <u> </u> | ocuments have been received. Incuments have been received in Apolithe priority documents have been all Bureau (PCT Rule 17.2(a)). | oplication No received in this National Stage | | | | |
| Attachment(s) | _ | | | | | |
| Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO | 4) Interview S | ummary (PTO-413) /Mail Date | | | | |
| Notice of Draitspersor's Fatetit Drawing Review (FTO) Information Disclosure Statement(s) (PTO-1449 or PT Paper No(s)/Mail Date <u>01/210/04</u>. | | formal Patent Application (PTO-152) | | | | |

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DETAILED ACTION

Allowable Subject Matter

Claims 7-14 are allowed.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in a patent granted on an application for patent by another filed in the United States before the invention thereof by the applicant for patent, or on an international application by another who has fulfilled the requirements of paragraphs (1), (2), and (4) of section 371(c) of this title before the invention thereof by the applicant for patent.

The changes made to 35 U.S.C. 102(e) by the American Inventors Protection Act of 1999 (AIPA) and the Intellectual Property and High Technology Technical Amendments Act of 2002 do not apply when the reference is a U.S. patent resulting directly or indirectly from an international application filed before November 29, 2000. Therefore, the prior art date of the reference is determined under 35 U.S.C. 102(e) prior to the amendment by the AIPA (pre-AIPA 35 U.S.C. 102(e)).

Claims 1-6 are rejected under 35 U.S.C. 102(e) as being anticipated by US Patent No. 5,796,121 to Gates.

In regards to claim 1, Gates teaches a method of manufacturing a thin film transistor device, said method comprising: providing a substrate; forming a copper alloy line on said substrate, said copper alloy line including a concentration y of magnesium, and said copper alloy line having a thickness t, wherein the concentration y of magnesium in relation to the thickness t of said copper alloy line is and

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heat-treating said copper alloy line in an oxygen atmosphere at column 9, lines 57-61.

In regards to claim 2, Gates teaches the method of claim 1, wherein said heat-treatment is performed at a temperature in the range of about 250°C to about 500°C at column 7, lines 18-24.

In regards to claim 3, teaches the method of claim 1, wherein said heat-treatment is carried out at a temperature of about 350°C and in a vacuum of about 10 mTorr.

In regards to claim 4, Gates teaches the method of claim 1, wherein said step of heat-treating is performed using Ar plasma at column 7, lines 1-5.

In regards to claim 5, Gates teaches the method of claim 4, wherein the temperature during said Ar plasma heat-treating is about 100°C at column 7, lines 1-5.

In regards to claim 6, Gates teaches the method of claim 1, wherein a concentration of oxygen contained in the copper alloy at column 4, lines 13-19.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Renee R Berry whose telephone number is (571) 272-1774. The examiner can normally be reached on M-F 9-5:30.

The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

RRB

September 25, 2004

John F. Niebling

Súpervisory Patent Examiner Technology Center 2800